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Slope and amplitude asymmetry effects on low frequency capacitively coupled carbon tetrafluoride plasmas

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We report investigations of capacitively coupled carbon tetrafluoride (CF₄) plasmas excited with tailored voltage waveforms containing up to five harmonics of a base frequency of 5.5 MHz. The impact of both the slope asymmetry, and the amplitude asymmetry, of these waveforms on the discharge is examined by combining experiments with particle-in-cell simulations. For all conditions studied herein, the discharge is shown to operate in the drift-ambipolar mode, where a comparatively large electric field in the plasma bulk (outside the sheaths) is the main mechanism for electron power absorption leading to ionization. We show that both types of waveform asymmetries strongly influence the ion energy at the electrodes, with the particularity of having the highest ion flux on the electrode where the lowest ion energy is observed. Even at the comparatively high pressure (600 mTorr) and low fundamental frequency of 5.5 MHz used here, tailoring the voltage waveforms is shown to efficiently create an asymmetry of both the ion energy and the ion flux in geometrically symmetric reactors. *Published by AIP Publishing.*

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I. INTRODUCTION

Capacitively coupled radio frequency (CCRF) plasmas are commonly used in a wide range of applications, including thin film deposition and plasma etching, with end products in the semiconductor industry or in the medical sector.¹ In the case of plasma etching, electronegative gases such as carbon tetrafluoride (CF₄) are generally used,² often driven by a low frequency³ of a few megahertz. These processes usually require control of the ion flux as well as the ion energy, a feature unachievable in classical single frequency CCRF discharges.⁴ It is possible, however, to control the ion energy using well-separated multiple frequencies or through frequency coupling of harmonics, for example, via the electrical asymmetry effect (EAE), independently of other plasma parameters and, in particular, independently of the ion flux.^{5–16} In this paper, we will investigate the effect of both amplitude asymmetric and slope asymmetric waveforms on ion properties in CF₄ plasmas.

According to an analytical model developed by Czarnetzki *et al.*, the appearance of a self-bias, η ,^{5–7} due to the EAE, can be expressed as

$$\eta = -\frac{\tilde{V}_{m1} + \varepsilon \tilde{V}_{m2}}{1 + \varepsilon}, \quad (1)$$

where \tilde{V}_{m1} and \tilde{V}_{m2} are the maximum and the minimum (relative to the temporal average) of the applied voltage waveform $V_{AC}(t)$, respectively, and ε is the symmetry parameter

$$\varepsilon = \left| \frac{\hat{V}_{sg}}{\hat{V}_{sp}} \right| \approx \left(\frac{A_p}{A_g} \right)^2 \left(\frac{Q_{mg}}{Q_{mp}} \right)^2 \frac{\bar{n}_{sp}}{\bar{n}_{sg}}, \quad (2)$$

where \hat{V}_{sp} and \hat{V}_{sg} are the maximum sheath voltages across the sheaths at the powered and grounded electrodes, respectively; A_p and A_g are the area of the powered and the grounded electrodes; Q_{mg} and Q_{mp} are the maximum unbalanced charges in the respective sheaths; and \bar{n}_{sp} and \bar{n}_{sg} are the respective mean ion densities in the sheaths. Following the pioneering work of Wendt *et al.*,^{17,18} waveforms comprising multiple harmonics of the same fundamental frequency, f , known as Tailored Voltage Waveforms (TVWs), have been shown to provide yet more control of the EAE compared to the two-frequency case.¹⁹ Such amplitude asymmetric waveforms are based on the following form for the driving voltage waveform:²⁰

$$V_{AC}(t) = V_0 \sum_{k=1}^N \frac{N-k+1}{N} \cos(k\omega t + \Theta), \quad (3)$$

where V_0 is a voltage amplitude factor, N is the number of harmonics (here varied between one and five), $\omega = 2\pi f$ is the angular frequency (here corresponding to a frequency $f = 5.5$ MHz), and Θ is a phase shift. V_0 is set to give the

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desired peak-to-peak voltage, V_{PP} . The amplitudes of the individual harmonics are chosen to maximize the amplitude asymmetry of the waveform ($\tilde{V}_{m1}/\tilde{V}_{m2}$) and, therefore, maximize the accessible range of the DC self-bias according to Eq. (1).²⁰ The phase shift Θ can be varied to control the amplitude asymmetry from a maximum ($\Theta = 0$) to a minimum ($\Theta = \pi$). Such waveforms, with $N = 4$, are shown in Fig. 1(a) for different values of Θ .

Alternatively, it was recently shown^{21–23} that some control over the asymmetry of argon discharges can be obtained using sawtooth waveforms (i.e., with differing rise and fall rates), defined by the following expression:

$$V_{AC}(t) = \pm V_0 \sum_{k=1}^N \frac{1}{k} \sin(k\omega t). \quad (4)$$

The slope asymmetry of the waveform can then be controlled by the number of frequencies, N . The $1/k$ pre-factors are chosen to maximize the slope asymmetry for a given N . The minus sign in Eq. (4) corresponds to sawtooth-up waveforms, while the plus sign corresponds to sawtooth-down waveforms. Such waveforms, with different N , are shown in Fig. 1(b) (the case $N = 1$ corresponds to a pure sinusoid). Here, the increase of the rising slope with N can be clearly observed. These waveforms were shown to induce a fast sheath expansion and a slow sheath contraction in front of one electrode, and a slow sheath expansion and a fast sheath contraction on the other side.²³ As a consequence, a strong asymmetry of the electron power absorption (and therefore

the ionization rate) can be produced in geometrically symmetric argon discharges, with larger ionization closer to the electrode where the sheath expands rapidly. A DC self-bias was also shown to appear in argon discharges in this case, despite the absence of an amplitude asymmetry (i.e., $\tilde{V}_{m1} = \tilde{V}_{m2}$), because of different mean ion densities in the sheaths ($\varepsilon \neq 1$ in Eq. (1)), and therefore different ion fluxes at the electrodes.

More recently, Bruneau *et al.*²⁴ have studied the impact of waveforms with continuously changing amplitude and slope asymmetry, obtained by slightly shifting the higher frequencies from the harmonics. These waveforms are shown to control the shape of the ion flux distribution function and, in particular, its width, while keeping the ion flux and mean ion energy constant. They are, however, not used in the present study.

Although the impact of the amplitude and slope asymmetry of a waveform has been studied in detail in argon discharges,^{6–12,21–23} only one article by Schulze *et al.*²⁵ has looked at the effect of TVWs on CF_4 discharges, and it is briefly studied in an article by Bruneau *et al.*²⁶ The former study contained only simulations with no experimental measurements and was limited to two harmonics. Furthermore, there is an interest in studying the behavior of CF_4 discharges when excited with low fundamental frequencies, as used in etching applications.³ In the present paper, the results of particle-in-cell (PIC) simulations are compared to experimental results, including phase-resolved optical emission spectroscopy (PROES) measurements. The impacts of both the amplitude and the slope of the waveform are investigated, using up to five harmonics with a fundamental frequency of 5.5 MHz.

II. METHODS

A. Simulations

The simulations consider four types of charged species: CF_3^+ , CF_3^- , F^- ions, and electrons. Although more species may be present, it has been shown in previous studies that these are the dominant ones.^{27–33} The energy-dependent cross sections for the electron- CF_4 collision processes are presented in Fig. 2(a). The cross-sections are taken from Kurihara *et al.*,³⁴ except for electron attachment processes which are taken from Bonham *et al.*³⁵ A complete list of the electron impact collision processes used in this model can be found in Schulze *et al.*²⁵ Although a large number of ion- CF_4 reactions take place in CF_4 discharges,^{27,32,36} only a limited set of reactions are included here. The energy dependent cross sections for these reactions are shown in Fig. 2(b). These collision processes include reactive as well as elastic collisions of different ions with CF_4 . Because of the significant negative ion densities in these plasmas, recombination processes between positive and negative ions, as well as between electrons and CF_3^+ , must be taken into account. These processes are simulated following the procedure by Nanbu and Denpoh.³⁷ The rate of the electron- CF_3^+ recombination is taken from Denpoh and Nanbu.³⁸

The interelectrode distance is set to 2.5 cm, and the neutral gas is assumed to be uniformly distributed with a

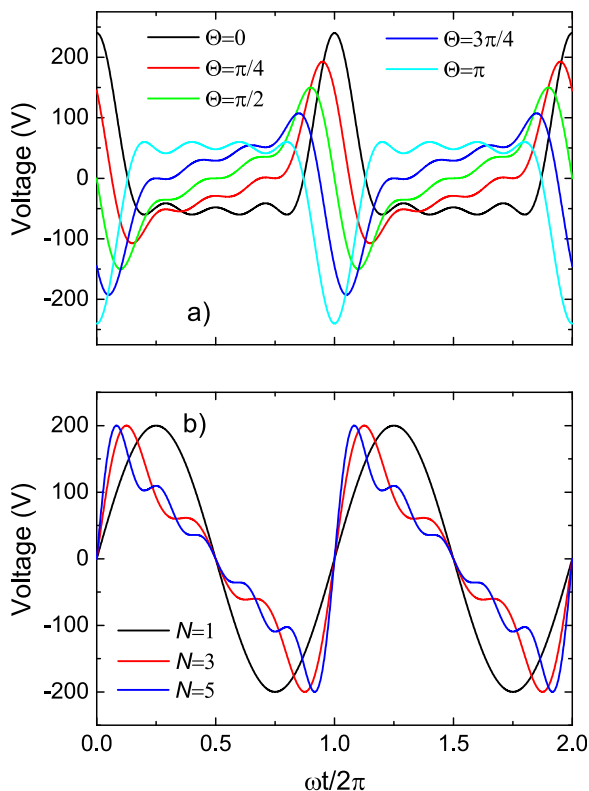


FIG. 1. (a) Waveforms according to Eq. (3) with different phase shifts, Θ , and (b) waveforms according to Eq. (4), corresponding to sawtooth-down waveforms, for different numbers of harmonics N .

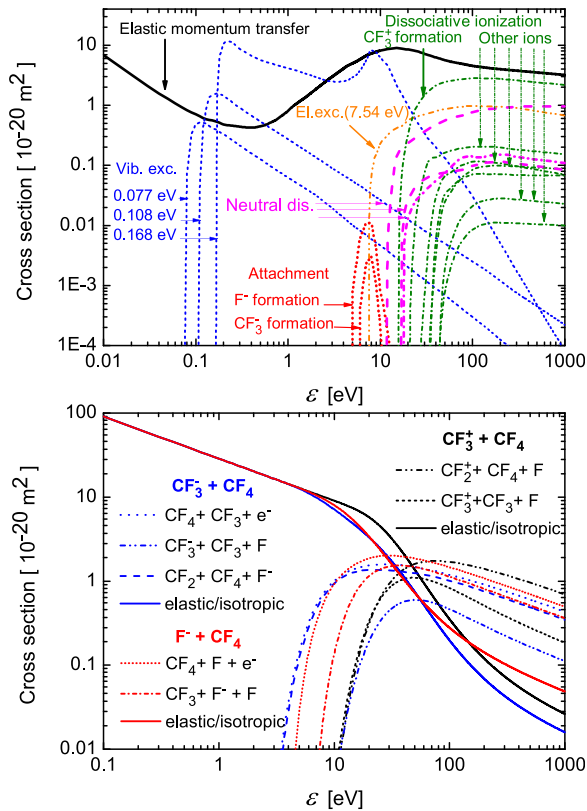


FIG. 2. Cross sections of electron-impact (a) and ion-impact (b) collision processes included in the simulations as a function of the electron and ion incident energy, respectively. Sources for the cross-sections are given in the text.

temperature of 350 K. Electrons hitting the electrodes are reflected with a probability of 20%,³⁹ while the ion-induced emission of secondary electrons, γ , is set to 0.

The DC self-bias in the simulations is determined as follows: at the beginning of the simulations, a bias of 0 V is set. After executing the simulation for 100 RF cycles, the fluxes of the positively and negatively charged particles to each of the two electrodes are evaluated. Depending on the balance of these fluxes, the DC self-bias is changed by a small value. This procedure is continued until the DC self-bias reaches a converged value, and the charged particle fluxes to each of the two electrodes are balanced.

B. Experiments

The experimental setup has been described in detail in Ref. 23. A reactor with an inter-electrode gap of 2.5 cm was made geometrically symmetric by adding a thick Teflon ring (inner diameter 10 cm), fitted with a $2.5 \times 2.5 \times 10$ cm piece of borosilicate glass to allow optical access. The working pressure was varied between 50 mTorr and 600 mTorr in the experiments. The voltage waveform was generated using a computer-controlled arbitrary function generator (AFG) and a broadband power amplifier as described previously.¹⁹ The true delivered waveform is monitored by a high voltage probe, and the waveform is corrected for distortion using a feedback loop as proposed by Patterson *et al.*¹⁸ Phase-resolved images of the plasma-induced optical emission are recorded with an intensified charge-coupled device (ICCD)

camera (Andor iStar), which is synchronized to the AFG, and the phase varied using a delay generator. The gate time of the camera is 2 ns, therefore giving 91 images within one RF-cycle for a fundamental frequency of 5.5 MHz. The excitation rate at each position and phase is derived from the measured emission from the F atom line at 703.7 nm, using the deconvolution method proposed in Ref. 40, and is compared to the dissociative ionization rate from the simulations. The electron energy thresholds are 14.7 eV (Ref. 41) for electron-impact excitation of the emitting state from ground state F atoms (experimentally observed) and 16 eV for dissociative ionization (used in the simulations), respectively. Although two different processes are compared, these processes have similar energy thresholds and will therefore probe in a comparable way the high energy electron population. This strategy therefore limits us to a qualitative comparison of the dynamics of energetic electrons. A more thorough way of addressing this issue would be to include the F atom distribution in the simulations. Such a refinement, which remains for future work, may lead to the possibility of a more quantitative comparison between experiment and simulation.

III. RESULTS

In the following, the impact of waveforms with an amplitude asymmetry (according to Eq. (3)) on a CF₄ discharge is investigated in Section III A, while in Section III B, we focus on the impact of waveforms with a slope asymmetry (according to Eq. (4)). In both cases, the excitation rates and the DC self-bias are compared between the simulations and the experiments, and the simulations are used to investigate the impact of TVWs on the ion flux and the ion flux-energy distribution function (IFEDF) at each electrode, since these could not be measured here.

A. Amplitude asymmetry

In this case, waveforms according to Eq. (3) are used, with $N = 4$, and the phase shift Θ is varied to control the amplitude asymmetry of the waveform. The neutral gas pressure is kept constant at 600 mTorr, and V_0 is set to 96 V (giving a peak-to-peak voltage $V_{PP} = 300$ V for $\Theta = 0$).

Figure 3 shows the DC self-bias, η , observed experimentally and given by the simulations as a function of Θ . The agreement is good for almost all values of Θ , except for $\Theta = 0.75\pi$ and $\Theta = 1.75\pi$. The DC self-bias voltage, η , increases as Θ is increased between 0 and π , and then decreases, consistent with the amplitude ratio $\tilde{V}_{m1}/\tilde{V}_{m2}$, which decreases in the first range and increases in the second one. It is worth noting that the variation of the DC self-bias with Θ is not as linear as in argon.²¹ Indeed, for Θ lower than 0.5π , it only slightly increases with Θ , whereas it increases more significantly for Θ between 0.5π and π . Overall, the range over which the DC self-bias can be controlled is significantly larger than that observed previously in the case of argon,^{10,12,20} or in CF₄²⁵ (although only two frequencies have been used in the latter case).

In the following, Θ is varied only between 0 and π , since for Θ between π and 2π , the discharge is simply a

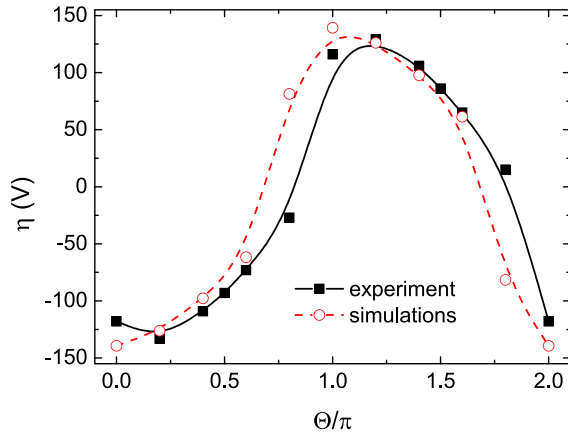


FIG. 3. DC self-bias, η , as a function of Θ . The black solid line and squares represent the experimental results, and the red dashed line and circles represent the results of PIC simulations.

mirror image of that for Θ between 0 and π . Figure 4 shows the spatio-temporal dependence of the excitation rate, derived from the experimentally measured optical emission of the F line at 703.7 nm (top row), compared to the rate of CF_4 dissociative ionization obtained from simulations (middle row), as a function of Θ from 0 to π (from left to right). As mentioned in Section II, F atom excitation and CF_4 dissociative ionization by electron impact have similar electron energy thresholds (of 14.5 and 16 eV, respectively), and should therefore have rates that vary in a similar way with electron density and temperature. The x -axis represents position (with the powered electrode at $x=0$ cm and the grounded electrode at $x=2.5$ cm), while the y -axis represents time, and spans one fundamental RF cycle. The sheath edge position is obtained from the simulations using the Brinkmann criterion⁴² and is shown as a white line in the simulation plots. The images are normalized to the maximum

of the excitation (or ionization) of the case at $\Theta=0.5\pi$. Also shown in the bottom row is the dynamics of the electric field outside the sheath region (the latter being shown in black) obtained from the simulations.

The agreement between the experiments and the simulations is very good. The only significant difference is observed for $\Theta=0.75\pi$, which is a region where the discharge asymmetry depends strongly on Θ , as already observed in the DC self-bias voltage in Fig. 3. Therefore, a small difference in Θ between the experiments and the simulations will lead to large changes in the excitation dynamics. It should be noted that, in the experiments, a difference can be observed between the cases $\Theta=0$ and $\Theta=\pi$, whereas they should be mirror images of each other. This small discrepancy can be attributed either to imperfect optical alignment or to residual geometric asymmetry of the reactor.

Looking at the cases with Θ between 0 and 0.5π , one can see that the highest ionization peak occurs close to the grounded electrode during sheath contraction. This is the opposite of what has been observed for argon,⁹ where the highest ionization occurs at the sheath edge during sheath expansion. This can be explained by the different dominant electron power absorption mechanisms in Ar and CF_4 . In Ar, electrons gain energy during the rf cycle predominantly by reflection from the expanding sheaths, whereas in CF_4 , electrons gain energy predominantly by the drift-ambipolar mechanism under many conditions, as described by Schulze *et al.*^{25,43} This can be observed in the bottom row of Fig. 4. Indeed, in this case, a strong electric field is present in the plasma bulk (outside the sheath). This field accelerates the electrons from the plasma centre towards the powered electrode. However, a floating potential sheath prevents these electrons from reaching the electrode, trapping them close to the electrode and creating a region with a high density of

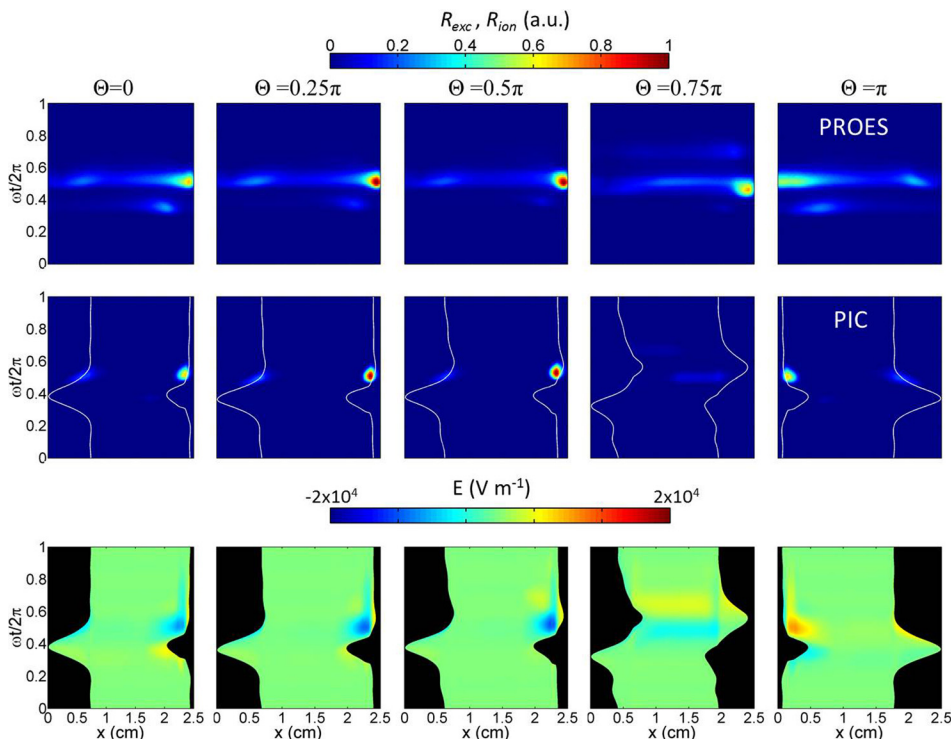


FIG. 4. Spatio-temporal excitation rate derived from measurements of the emission line at 703.7 nm using PROES (top row), rate of dissociative ionization (middle row), and electric field (bottom row) obtained from PIC simulations, using a waveform with $N=4$ harmonics according to Equation (3), for different values of Θ from 0 (left) to π (right). The x -axis represents position (with the powered electrode at $x=0$ cm and the grounded electrode at $x=2.5$ cm), while the y -axis represents time, and spans one fundamental RF cycle.

highly energetic electrons, thus significantly increasing the rates of dissociative ionization and excitation. These two regions with electric fields in opposite directions can be regarded as a double layer, which develops in strongly electronegative gas discharges, even in single frequency excitation.⁴⁴ The reasons for the development of such a structure in the case of multi-frequency excitation are studied in more detail in Ref. 45. The observed asymmetry therefore originates from the fact that this drift-ambipolar electric field only appears in front of a sheath which is rapidly collapsing.

Figure 5(a) shows the CF_3^+ flux at the powered and grounded electrodes obtained from the simulations. For $\Theta = 0$, the flux is highest at the grounded electrode, where the ion energy is lowest (as can be inferred from the large negative self-bias shown in Fig. 3 in this case). This is different from the case of argon, where the flux is highest at the electrode where the ion energy is highest.²¹ This is due, again, to the strong drift-ambipolar electric field which builds up in the plasma bulk in front of the grounded electrode sheath when it contracts. When Θ is increased to $\Theta = 0.5\pi$, the ion flux increases at the grounded electrode and decreases at the powered electrode, giving a flux 2.5 times larger at the grounded electrode compared to the

powered one. When Θ is further increased, the ion flux at the grounded electrode decreases strongly, reaching a minimum for Θ around 0.75π . This reduction is consistent with the lower ionization rate observed in Fig. 4, and with a significant change in the electric field dynamics.

Figure 5(b) shows the mean ion energy, $\langle E_i \rangle$, at the powered and grounded electrodes obtained from the simulations. For $\Theta = 0$, the mean ion energy is close to 50 eV at the powered electrode, and only about 6 eV at the grounded electrode, i.e., the ratio of the mean energy values at the two electrodes is about eight. This result is surprising at such a high pressure, where the collisionality in the sheaths is high. This ratio is much larger than that obtained with two frequencies by Schulze *et al.*²⁵ at a fundamental frequency of 13.56 MHz. The increase in the number of harmonics cannot explain this increase, and it must therefore be caused by the difference in the fundamental frequency. Such a study is, however, out of the scope of this paper and will be presented elsewhere.⁴⁵ This result indicates that TVWs allow control of the ion energy over a large range in CF_4 when the fundamental frequency is low, even at high pressures.

As a consequence of both the DC self-bias and the CF_3^+ flux dependence on Θ , the ion flux-energy distribution function (IFEDF) evolution with Θ is non-trivial. The IFEDF, obtained from the simulations, is shown in Figs. 5(c) and 5(d) for the grounded and powered electrodes, respectively. Note that the IFEDF is shown in log-scale. At the grounded electrode, the maximum ion energy remains low for Θ/π below 0.7, which is consistent with the strong negative DC self-bias. Above this value, the maximum ion energy greatly increases, as a consequence of the increase of the DC self-bias, while the maximum of the IFEDF decreases, consistent with the reduction of the ion flux. The exact opposite occurs at the powered electrode.

B. Slope asymmetry

In the following, sawtooth waveforms according to Eq. (4) are used, and the number of harmonics composing the waveform N is varied to control the slope asymmetry of the waveform. The fundamental frequency is set to 5.5 MHz, and the peak-to-peak voltage is 400 V. In Ar, the strongest asymmetry was obtained at high pressures;²² therefore, we first examine the results at 600 mTorr. In addition, it was shown that the electronegativity of CF_4 discharges increases with pressure.²⁵ Therefore, we investigated the effect of pressure on the discharge asymmetry over the range 50–600 mTorr.

1. High pressure regime (600 mTorr)

Figure 6(a) shows the DC self-bias obtained, when the discharge is excited with sawtooth-up and sawtooth-down waveforms. Full symbols and solid lines represent the experimental data, while the simulation results are represented by open symbols and dashed lines. The agreement between the simulations and the experiments is good, except for the case $N = 2$, for which the simulations yield a significantly higher DC self-bias compared to the experiments. The reason for this discrepancy, despite the good agreement for the other cases, is still unclear.

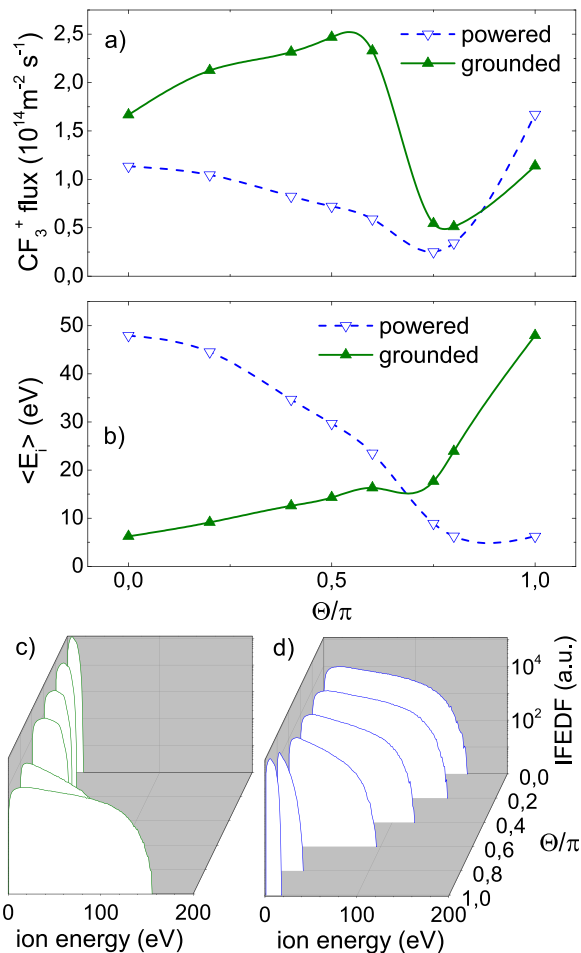


FIG. 5. Flux (a) and mean ion energy, $\langle E_i \rangle$, (b) of CF_3^+ ions at the powered (blue dashed line and down-triangles) and grounded (green solid line and up-triangles) electrodes; CF_3^+ flux-energy distribution function at the grounded (c) and powered (d) electrodes; these results have been obtained from the simulations.

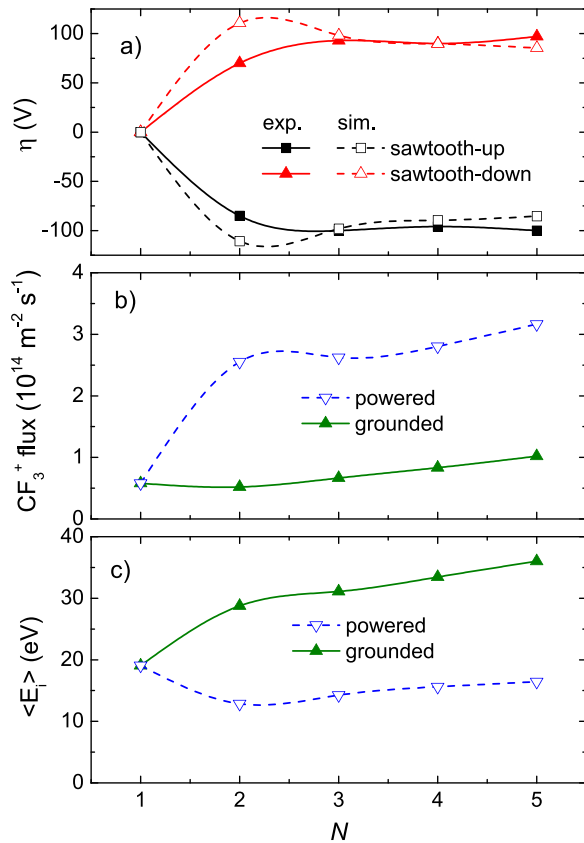


FIG. 6. (a) DC self-bias voltage, η , experimentally measured (solid lines and full symbols), and obtained from PIC simulations (dashed lines and open symbols), for sawtooth-up (black lines and up-triangles) and sawtooth-down (red lines and down-triangles) waveforms; (b) CF_3^+ flux, at the powered (blue dashed line and down-triangles) and grounded (green solid line and up-triangles) electrodes, for a sawtooth-down waveform, obtained from the simulations; (c) mean ion energy, $\langle E_i \rangle$, of CF_3^+ ions at the powered (blue dashed line and down-triangles) and grounded (green solid line and up-triangles) electrodes, for a sawtooth-down waveform, obtained from the simulations; these results are shown as a function of N .

The sawtooth-up waveforms lead to a negative DC self-bias, while the sawtooth-down waveforms give a positive one. This is the opposite of what was observed for Ar.^{22,23} In addition, the amplitude of the normalized DC self-bias can be more than two times higher than that obtained in Ar. Finally, whereas the DC self-bias continuously increases in argon as more harmonics are added, this is not the case for CF_4 discharges, as no increase, or even a small decrease, is observed when increasing N from 3 to 5. The reason for this behavior lies in the CF_3^+ flux to the electrodes. Indeed, as mentioned in the Introduction, whereas $\tilde{V}_{m1} = \tilde{V}_{m2}$ for these waveforms, the mean ion density at the sheath edges may differ, and so may the ion fluxes, leading to the appearance of a DC self-bias. We will see below that the ionization is highly asymmetric, leading to a large difference in the mean ion density in the two sheaths (e.g., $\bar{n}_{sp} > \bar{n}_{sg}$), leading to a symmetry parameter different from one according to Eq. (2) (e.g., $\varepsilon > 1$) and, therefore, to a non-zero self-bias according to Eq. (1) (e.g., $\eta > 0$).

Figure 6(b) shows the CF_3^+ flux at the powered and grounded electrodes obtained from the simulations, for discharges excited with a sawtooth-down waveform. Whereas

the ion flux at the grounded electrode increases only slightly with N , the ion flux at the powered electrode increases by a factor of 4.5 when N is increased from 1 to 2, and then continues to slowly increase when N is further increased. As a consequence, the highest flux ratio of about 5 (with a higher flux at the powered electrode) is obtained for $N=2$. Therefore, the larger asymmetry in the normalized DC self-bias is linked to a larger asymmetry in the ion fluxes.

Figure 6(c) displays the mean ion energy, $\langle E_i \rangle$, at the powered and grounded electrodes obtained from the simulations. As one can see, and as expected from the positive DC self-bias, the ion energy is lower at the powered electrode. The ratio of the mean ion energy at both electrodes changes little as N is varied, with a value of about 2.2. Therefore, for $N > 1$, the ion flux is highest at the electrode where the ion energy is lowest.

In order to better understand how large the discharge asymmetry is at these conditions, Fig. 7 shows the simulated IFEDF at the powered and grounded electrodes with a sawtooth-down waveform for $N=2$ or $N=5$. Note that the vertical axis scale is logarithmic. As mentioned before, for $N=2$, the total ion flux obtained at the powered electrode is five times higher than at the grounded electrode. However, this figure also shows that the ion energy at the powered electrode is significantly lower, with a mean ion energy lower by a factor of two. Of interest is also the maximum ion energy, which was shown in Refs. 46 and 47 to be of great importance as far as material treatment is concerned, and which is four times lower at the powered electrode in the case $N=2$. For the case $N=5$, the asymmetry is slightly lower but remains very large (the ion flux is three times higher on the powered electrode, the mean ion energy is two times lower, and the maximum ion energy is three times lower).

Figure 8 shows the excitation rate extracted from F atom optical emission (top row), which is compared to the rate of dissociative ionization obtained from the simulations (second row), when the discharge is excited with a sawtooth-down waveform with $N=1$ to 5 (from left to right). The data for

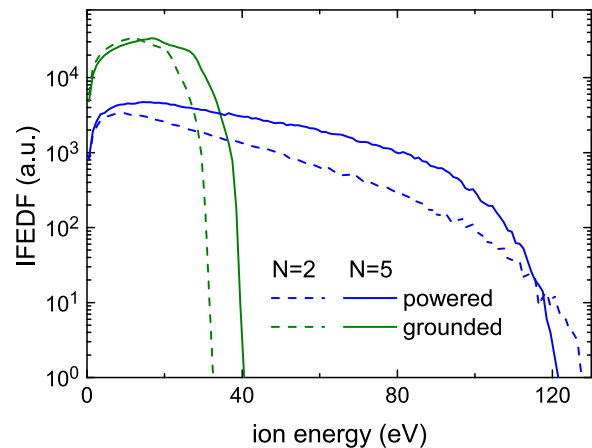


FIG. 7. Ion Flux-Energy Distribution Function (IFEDF) at the powered (blue lines) and grounded (green lines) electrodes for a sawtooth-down waveform with $N=2$ (dashed lines) or $N=5$ (solid lines), obtained from the simulations.

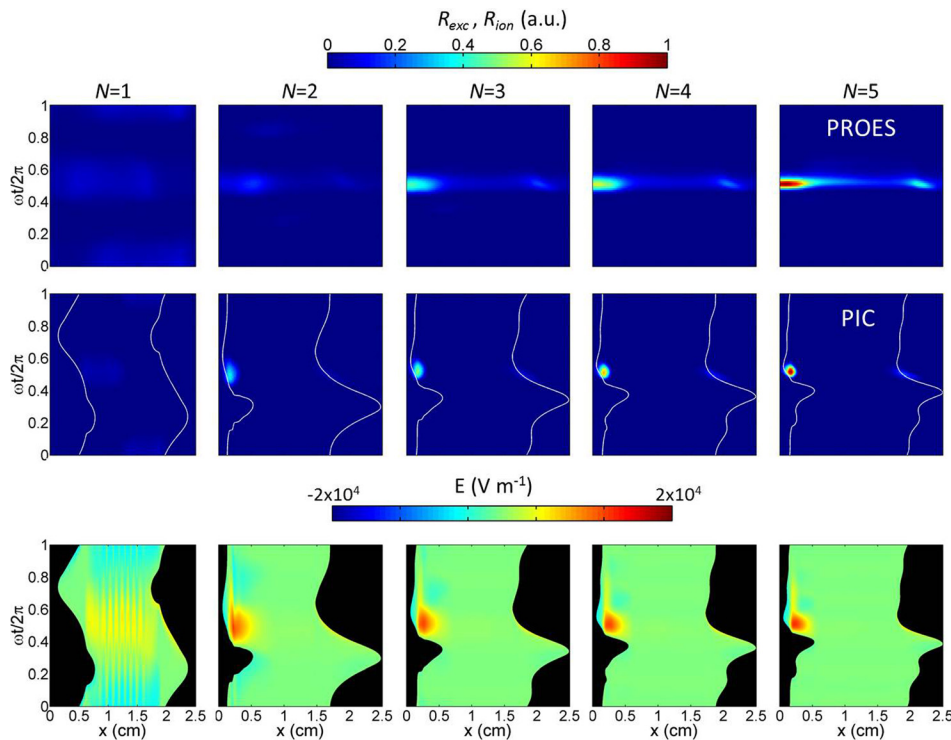


FIG. 8. Spatio-temporal excitation rate derived from measurement of the emission line at 703.7 nm using PROES (top row), the rate of dissociative ionization (middle row), and electric field (bottom row) obtained from PIC simulations, using a sawtooth-down waveform with $N = 1$ to 5 (from left to right); the images are normalized by the maximum of the case with $N = 5$.

both the simulations and the experiments are normalized to the maximum of the case $N = 5$. The bottom row shows the dynamics of the electric field. The plots of the ionization rate also show the position of the edges of the sheaths. As N is increased, the excitation strongly increases close to the powered electrode as the sheath collapses, while it increases less at the grounded electrode as that sheath expands. The excitation peak due to sheath expansion is slightly larger in the experiments (in particular, for large N), presumably due to a small optical misalignment (see also Fig. 4), that tends to decrease the amplitude close to the powered electrode.

This strong excitation close to the powered electrode indicates a significant difference in the excitation dynamics in CF_4 plasmas compared to that observed in Ar. As shown in the bottom row of Fig. 8, this excitation occurs when a strong negative electric field appears close to this electrode, similar to what is observed in case of amplitude-asymmetric waveforms, indicating that the discharge is again operating in DA

mode under these conditions. Once again, a double-layer structure is observed,⁴⁴ which efficiently accelerates and traps electrons, leading to large excitation. The origin of the striations observed in the spatio-temporal electric field for the case $N = 1$ is unknown. They were not observed experimentally, possibly because of limited spatial resolution.

In order to demonstrate the importance of the discharge asymmetry under these conditions, Fig. 9 shows (time-integrated) pictures through the PROES window of a CF_4 discharge excited with a sawtooth-down waveform with $N = 1$ (left) and $N = 2$ (right). The arrows indicate the position of the powered (P.E.) and grounded (G.E.) electrodes. No post-processing was applied to these images, i.e., they correspond to what can be seen by the naked eye. The discharge is observed in the central square, corresponding to the window in the Teflon ring. Whereas the light emission is uniform across the electrode gap for sinusoidal excitation ($N = 1$), it is strongly localized close to the powered electrode for a

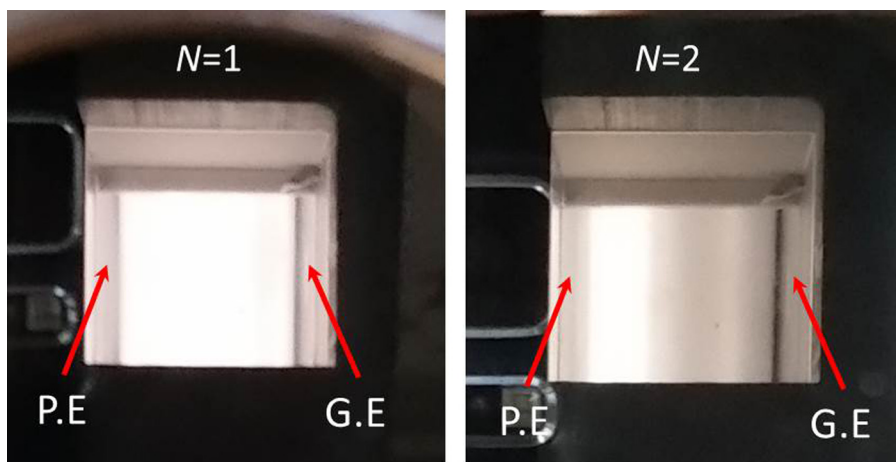


FIG. 9. Images taken through the PROES window of the CF_4 discharge excited with a sawtooth-down waveform with $N = 1$ (left) and $N = 2$ (right). The arrows indicate the position of the powered (P.E.) and grounded (G.E.) electrodes.

sawtooth waveform ($N=2$); the emission of almost one half of the discharge has been “turned off.” This is consistent with the PROES results shown in Fig. 2. Although not quantitative, these pictures give a visual impression of the strong impact of sawtooth waveforms on the spatial distribution of the discharge.

2. Effect of gas pressure

In this section, we explore how the effect of slope asymmetry depends on gas pressure. The other conditions are kept identical to those defined beforehand. It was shown previously that the gas pressure has a strong impact on the discharge asymmetry obtained with sawtooth waveforms in argon.²² Reducing the gas pressure increases the mean free path for energetic electrons, and this leads to changes to the spatial profiles of excitation and ionization. In addition, Schulze *et al.*⁴³ demonstrated that the impact of the DA heating decreases at lower pressure, which could also affect the discharge asymmetry.

Figure 10 shows the DC self-bias voltage, experimentally measured, and obtained from the PIC simulations, as a function of pressure p , for sawtooth-up and sawtooth-down waveforms, for (a) $N=2$, (b) $N=3$, and (c) $N=5$. The experimental trends are well reproduced by the simulations for each value of N .

In all cases, the DC self-bias voltage increases with pressure, similar to argon.²² For $N=2$, the DC self-bias increases linearly with pressure over the range investigated (both in the experiments and in the simulations), whereas for $N > 2$, a strong increase of the DC self-bias is observed at a pressure of about 200 mTorr, followed by a weaker increase when pressure is further increased.

In order to understand the different behaviour for $N=2$ and $N > 2$, Fig. 11 shows the rate of the dissociative ionization obtained from the simulations, for discharges excited with sawtooth-down waveforms with $N=2$ (first row) and $N=5$ (second row) for pressures of 50 mTorr, 150 mTorr, 300 mTorr, and 600 mTorr (from left to right). No normalization has been applied to these images.

It can be seen that for $N=2$, the excitation remains close to the powered electrode over this pressure range. Increasing the pressure only makes the excitation features more localized and draws them closer to the powered electrode, and no clear transition can be observed. In contrast, for $N=5$, at low pressure the maximum excitation is closer to the grounded electrode, possibly because electron energy gain from sheath expansion is comparable to or larger than the energy gain from the drift-ambipolar electric field. However, when the pressure is increased to 300 mTorr, a sharp transition occurs and the excitation becomes strongly localized close to the powered electrode, possibly because the drift-ambipolar electric field becomes the main source for electron energy gain. The fact that this transition occurs for $N=5$ but not for $N=2$ might be due to the fact that the energy gain by sheath expansion strongly depends on N , as it was observed in argon.²³ Therefore, the changes in the excitation dynamics explain why the DC self-bias shows a transition for $N > 2$ but not for $N=2$.

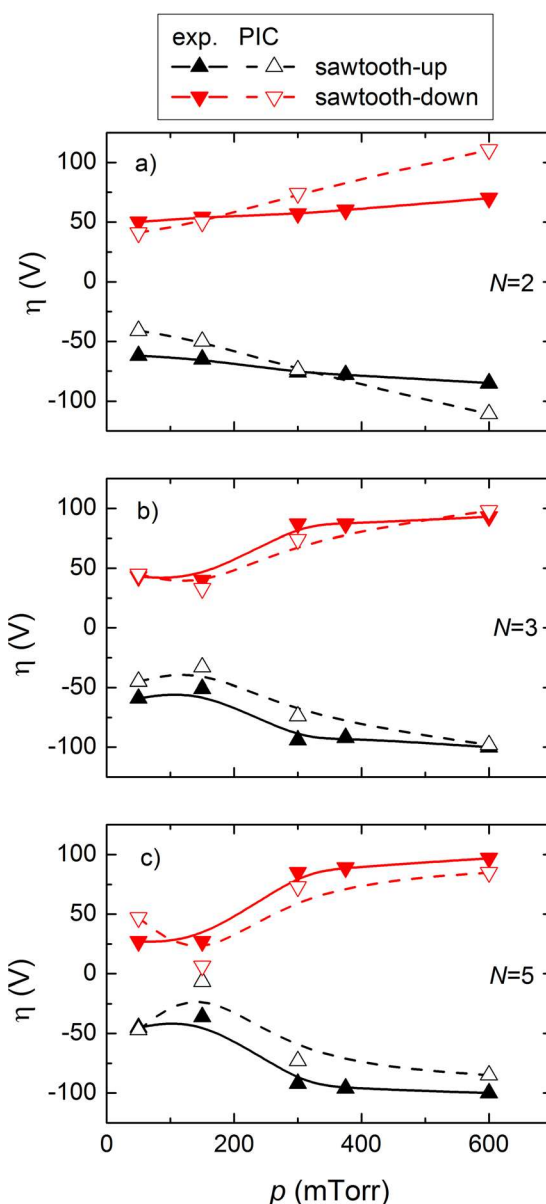


FIG. 10. DC self-bias voltage, experimentally measured (solid lines and full symbols), and obtained from PIC simulations (dashed lines and open symbols), as a function of pressure p , for sawtooth-up (black lines and up-triangles) and sawtooth-down (red lines and down-triangles) waveforms, for (a) $N=2$, (b) $N=3$, and (c) $N=5$.

IV. CONCLUSION

We have investigated the impact of amplitude and slope asymmetry of the driving voltage waveforms on the electrical asymmetry of geometrically symmetric CF_4 discharges. For all the conditions studied here, the discharge was found to operate in the DA mode, where a strong drift-ambipolar electric field adjacent to (but outside) the collapsing sheath is responsible for most of the ionization. Predictions of PIC simulations were found to be in good qualitative agreement with experimental data.

Controlling the amplitude asymmetry of the waveform via the phase shift Θ has been shown to be an efficient way of controlling the ion energy, with maximum energies up to nine times higher at one electrode compared to the other. However, at these high pressure conditions, significant

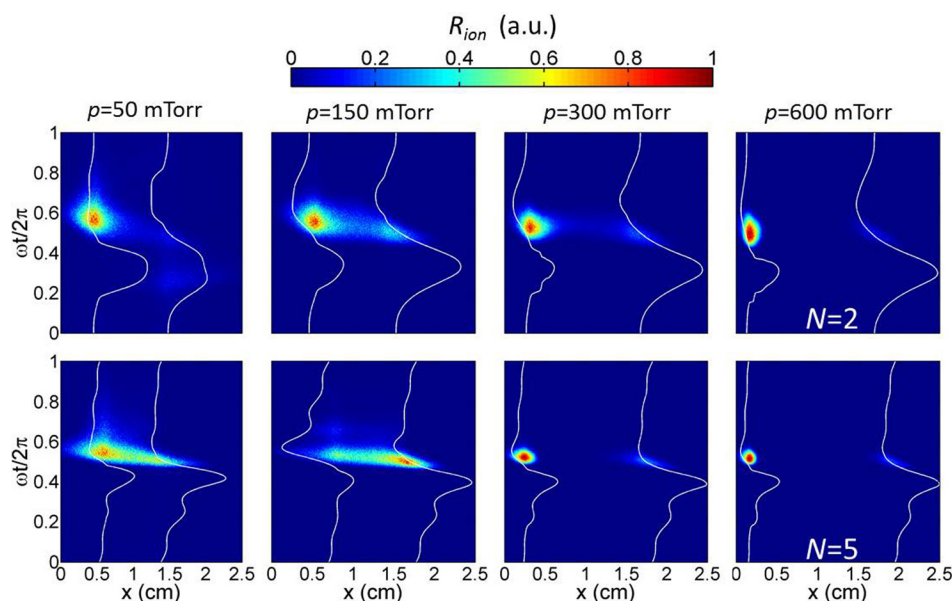


FIG. 11. Rate of dissociative ionization obtained from the simulations for a discharge excited with a sawtooth-down waveform for $N=2$ (first row) and $N=5$ (second row) for pressures of 50 mTorr, 150 mTorr, 300 mTorr, and 600 mTorr (from left to right).

changes in the ion flux also occur as Θ is varied. In particular, much lower ion fluxes are observed specifically for Θ around 0.75π , where the effects of the slope asymmetry and the amplitude asymmetry of the waveform balance each other out.

This effect in CF_4 occurs because, unlike for argon, the slope asymmetry of the waveform creates an ionization asymmetry as large as that created by the amplitude asymmetry. For instance, for some conditions, one electrode can have an ion flux five times higher than at the opposite electrode, while at the same time having a maximum ion energy four times lower. At lower pressures, electron energy gain via sheath expansion is more significant and can become comparable to that due to drift-ambipolar fields, therefore reducing the asymmetry.

To conclude, TVWs can be used to create a strong asymmetry of both the ion energy and the ion flux, even in geometrically symmetric reactors and with a low fundamental frequency. Larger (and inverted) effects are observed in electronegative gases (CF_4) compared to Ar, especially at higher pressure. This effect may be of potential interest for plasma etching applications.

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